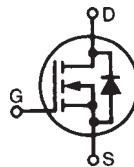


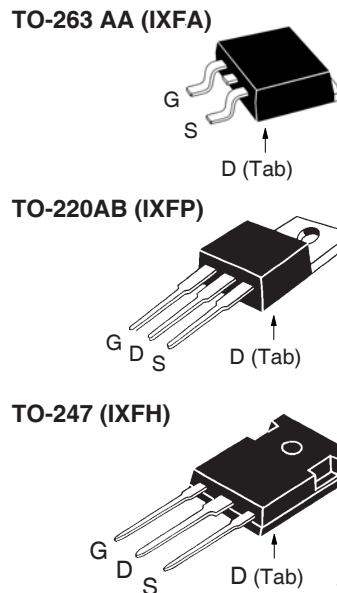
**TrenchT3™ HiperFET™  
Power MOSFET**
**IXFA220N06T3  
IXFP220N06T3  
IXFH220N06T3**
 **$V_{DSS}$  = 60V  
 $I_{D25}$  = 220A  
 $R_{DS(on)}$  ≤ 4mΩ**

N-Channel Enhancement Mode  
Avalanche Rated  
Fast Intrinsic Rectifier



Symbol	Test Conditions	Maximum Ratings		
$V_{DSS}$	$T_J = 25^\circ\text{C}$ to $175^\circ\text{C}$	60		V
$V_{DGR}$	$T_J = 25^\circ\text{C}$ to $175^\circ\text{C}$ , $R_{GS} = 1\text{M}\Omega$	60		V
$V_{GSM}$	Transient	±20		V
$I_{D25}$	$T_c = 25^\circ\text{C}$	220		A
$I_{LRMS}$	Lead Current Limit, RMS	160		A
$I_{DM}$	$T_c = 25^\circ\text{C}$ , Pulse Width Limited by $T_{JM}$	500		A
$I_A$	$T_c = 25^\circ\text{C}$	110		A
$E_{AS}$	$T_c = 25^\circ\text{C}$	900		mJ
$P_D$	$T_c = 25^\circ\text{C}$	440		W
$T_J$		-55 ... +175		°C
$T_{JM}$		175		°C
$T_{stg}$		-55 ... +175		°C
$T_L$ sold	Maximum Lead Temperature for Soldering 1.6 mm (0.062in.) from Case for 10s	300 260		°C
$F_c$ $M_d$	Mounting Force (TO-263) Mounting Torque (TO-220 & TO-247)	10..65 / 2.2..14.6 1.13 / 10	N/lb m/lb.in	
Weight	TO-263 TO-220 TO-247	2.5 3.0 6.0	g g g	

Symbol	Test Conditions ( $T_J = 25^\circ\text{C}$ Unless Otherwise Specified)	Characteristic Values		
		Min.	Typ.	Max.
$BV_{DSS}$	$V_{GS} = 0\text{V}$ , $I_D = 250\mu\text{A}$	60		V
$V_{GS(th)}$	$V_{DS} = V_{GS}$ , $I_D = 250\mu\text{A}$	2.0		4.0 V
$I_{GSS}$	$V_{GS} = \pm 20\text{V}$ , $V_{DS} = 0\text{V}$			±200 nA
$I_{DSS}$	$V_{DS} = V_{DSS}$ , $V_{GS} = 0\text{V}$ $T_J = 150^\circ\text{C}$			10 μA 1 mA
$R_{DS(on)}$	$V_{GS} = 10\text{V}$ , $I_D = 100\text{A}$ , Notes 1, 2			4 mΩ



G = Gate      D = Drain  
S = Source      Tab = Drain

**Features**

- International Standard Packages
- $175^\circ\text{C}$  Operating Temperature
- High Current Handling Capability
- Avalanche Rated
- Fast Intrinsic Rectifier
- Low  $R_{DS(on)}$

**Advantages**

- Easy to Mount
- Space Savings
- High Power Density

**Applications**

- DC-DC Converters & Off-Line UPS
- Primary-Side Switch
- High Current Switching Applications

Symbol	Test Conditions ( $T_J = 25^\circ\text{C}$ , Unless Otherwise Specified)	Characteristic Values		
		Min.	Typ.	Max.
$g_{fs}$	$V_{DS} = 10\text{V}$ , $I_D = 60\text{A}$ , Note 1	87	145	S
$C_{iss}$	$V_{GS} = 0\text{V}$ , $V_{DS} = 25\text{V}$ , $f = 1\text{MHz}$	8500	pF	
$C_{oss}$		970	pF	
$C_{rss}$		50	pF	
$R_{GI}$	Gate Input Resistance	1.7	$\Omega$	
$t_{d(on)}$	<b>Resistive Switching Times</b> $V_{GS} = 10\text{V}$ , $V_{DS} = 0.5 \cdot V_{DSS}$ , $I_D = 0.5 \cdot I_{D25}$ $R_G = 5\Omega$ (External)	24	ns	
$t_r$		20	ns	
$t_{d(off)}$		46	ns	
$t_f$		17	ns	
$Q_{g(on)}$	$V_{GS} = 10\text{V}$ , $V_{DS} = 0.5 \cdot V_{DSS}$ , $I_D = 0.5 \cdot I_{D25}$	136	nC	
$Q_{gs}$		44	nC	
$Q_{gd}$		30	nC	
$R_{thJC}$	TO-220	0.50	$^\circ\text{C}/\text{W}$	
$R_{thCS}$	TO-247	0.21	$^\circ\text{C}/\text{W}$	

#### Source-Drain Diode

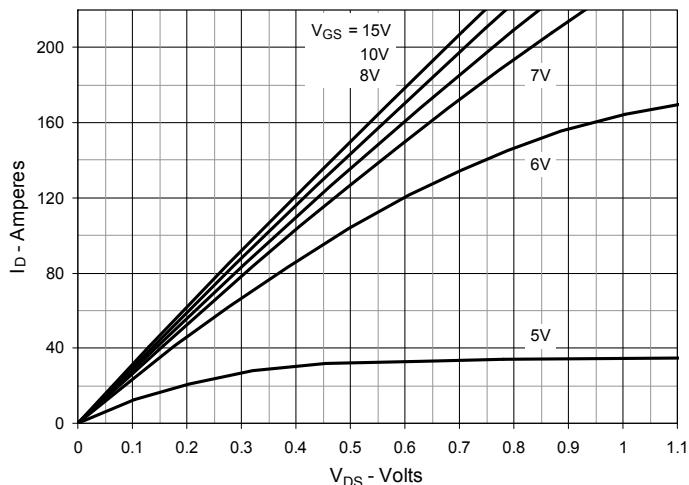
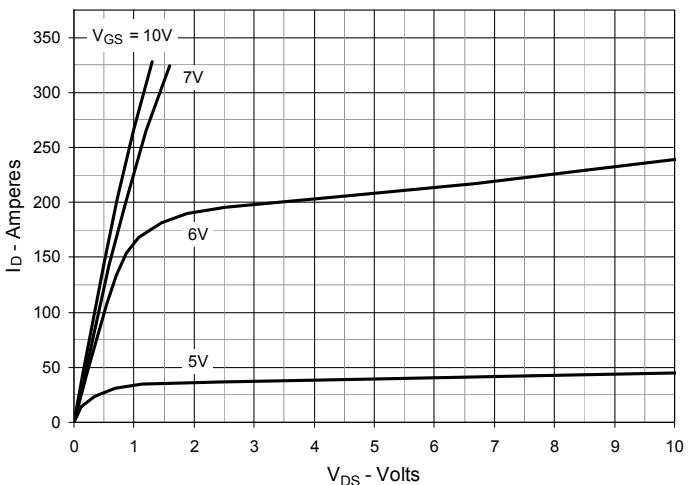
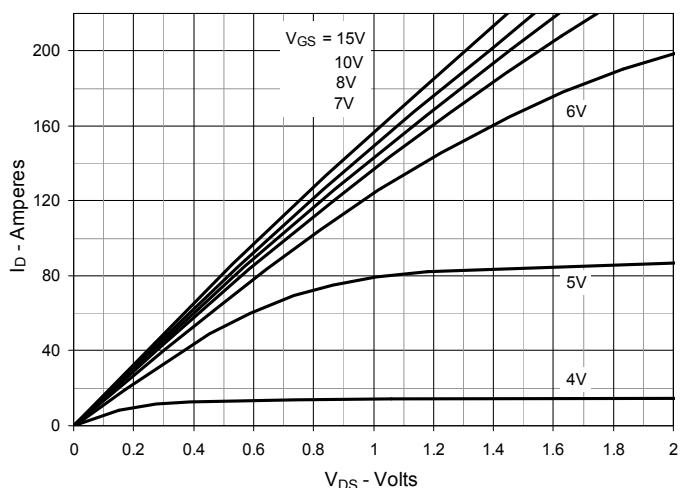
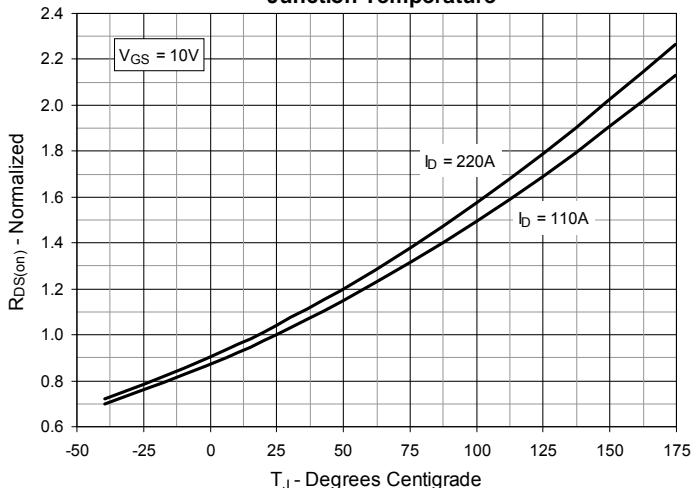
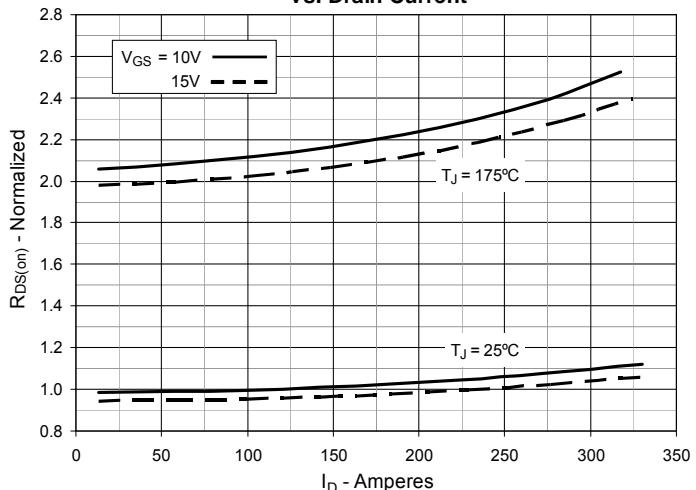
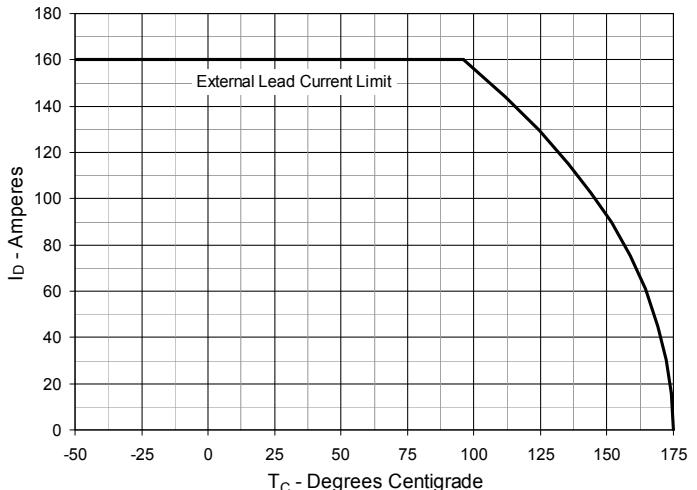
Symbol	Test Conditions ( $T_J = 25^\circ\text{C}$ , Unless Otherwise Specified)	Characteristic Values		
		Min.	Typ.	Max.
$I_s$	$V_{GS} = 0\text{V}$		220	A
$I_{SM}$	Repetitive, Pulse Width Limited by $T_{JM}$		880	A
$V_{SD}$	$I_F = 100\text{A}$ , $V_{GS} = 0\text{V}$ , Note 1		1.4	V
$t_{rr}$	$I_F = 110\text{A}$ , $V_{GS} = 0\text{V}$ $-di/dt = 100\text{A}/\mu\text{s}$ $V_R = 40\text{V}$	38	ns	
$I_{RM}$		1.9	A	
$Q_{RM}$		37	nC	

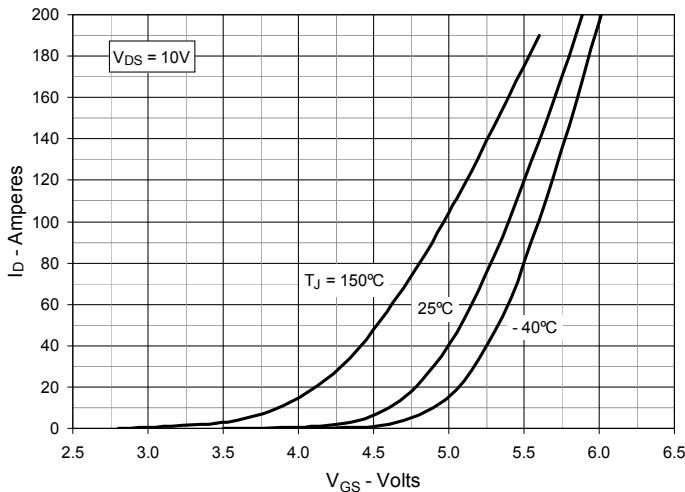
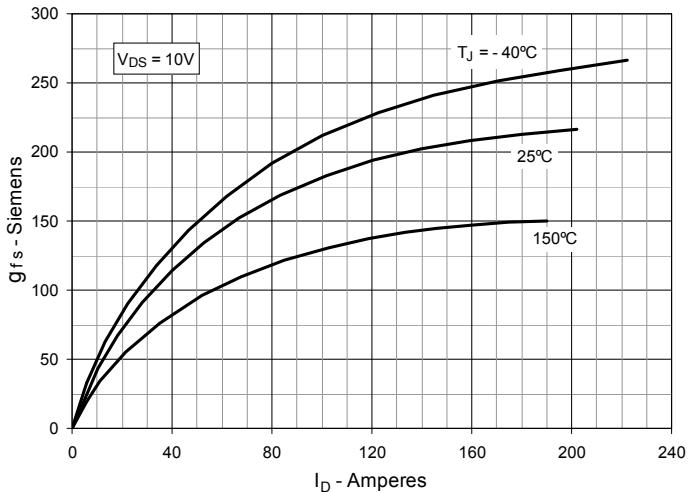
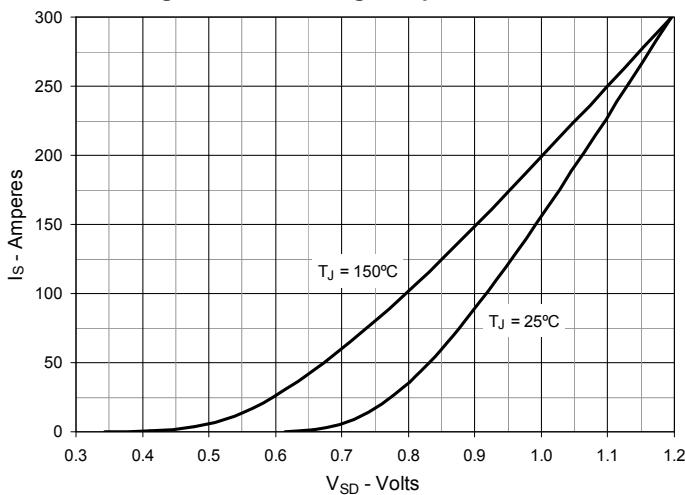
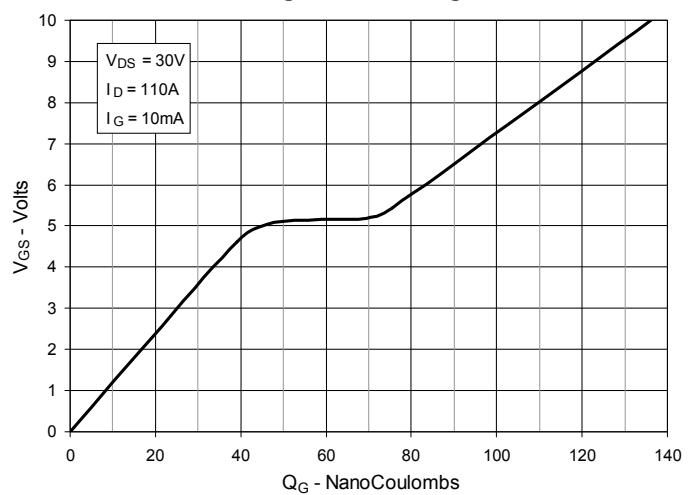
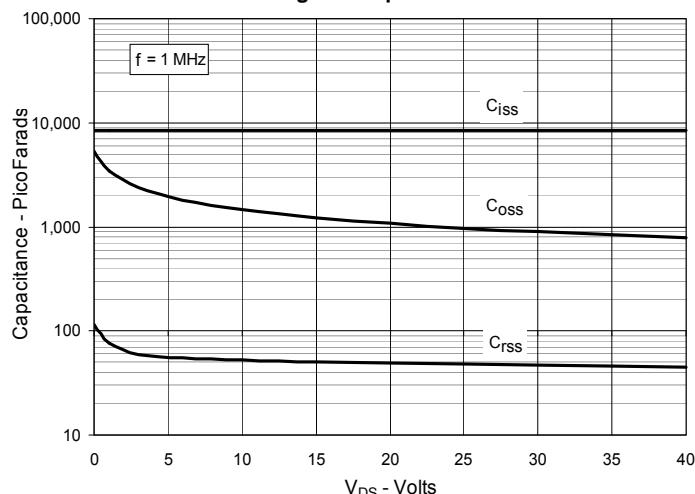
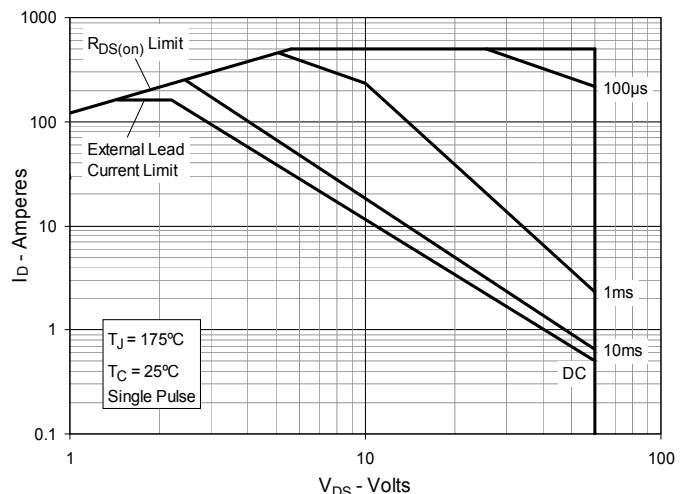
Notes:

1. Pulse test,  $t \leq 300\mu\text{s}$ , duty cycle,  $d \leq 2\%$ .
2. On through-hole packages,  $R_{DS(on)}$  Kelvin test contact location must be 5mm or less from the package body.

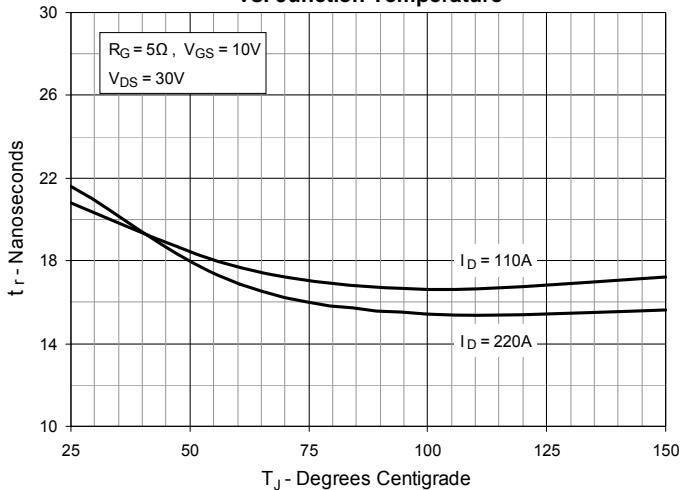
#### ADVANCE TECHNICAL INFORMATION

The product presented herein is under development. The Technical Specifications offered are derived from a subjective evaluation of the design, based upon prior knowledge and experience, and constitute a "considered reflection" of the anticipated result. IXYS reserves the right to change limits, test conditions, and dimensions without notice.

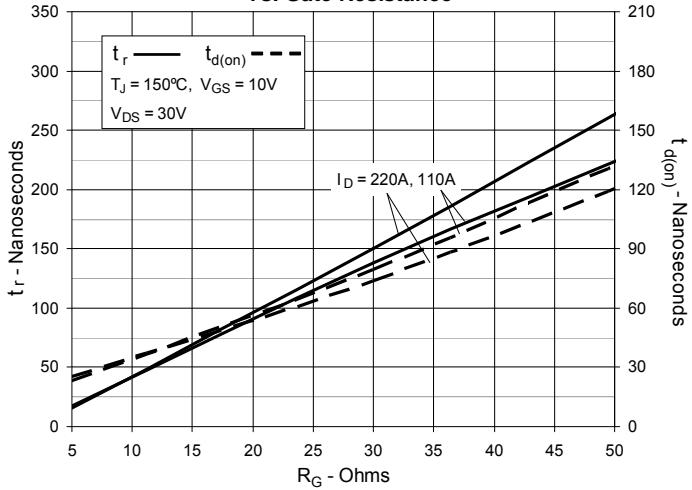
**Fig. 1. Output Characteristics @  $T_J = 25^\circ\text{C}$** 

**Fig. 2. Extended Output Characteristics @  $T_J = 25^\circ\text{C}$** 

**Fig. 3. Output Characteristics @  $T_J = 150^\circ\text{C}$** 

**Fig. 4. Normalized  $R_{DS(on)}$  to  $I_D = 110\text{A}$  Value vs. Junction Temperature**

**Fig. 5. Normalized  $R_{DS(on)}$  to  $I_D = 110\text{A}$  vs. Drain Current**

**Fig. 6. Drain Current vs. Case Temperature**


**Fig. 7. Input Admittance**

**Fig. 8. Transconductance**

**Fig. 9. Forward Voltage Drop of Intrinsic Diode**

**Fig. 10. Gate Charge**

**Fig. 11. Capacitance**

**Fig. 12. Forward-Bias Safe Operating Area**


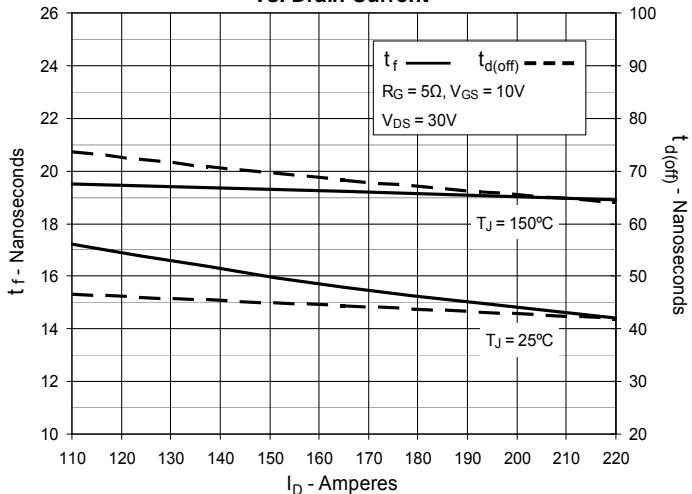
**Fig. 13. Resistive Turn-on Rise Time vs. Junction Temperature**



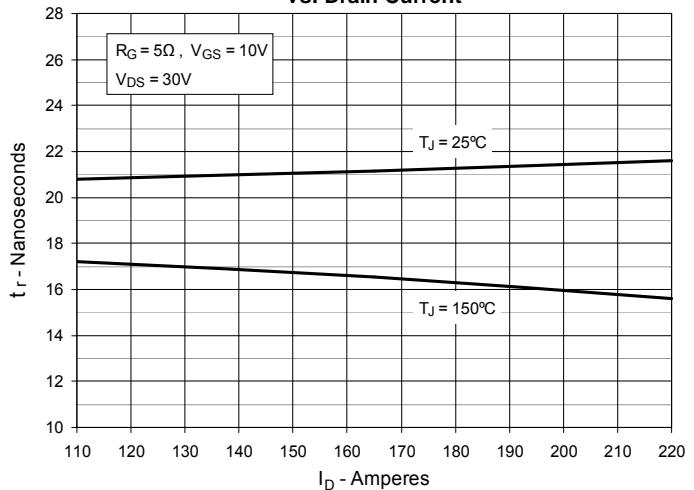
**Fig. 15. Resistive Turn-on Switching Times vs. Gate Resistance**



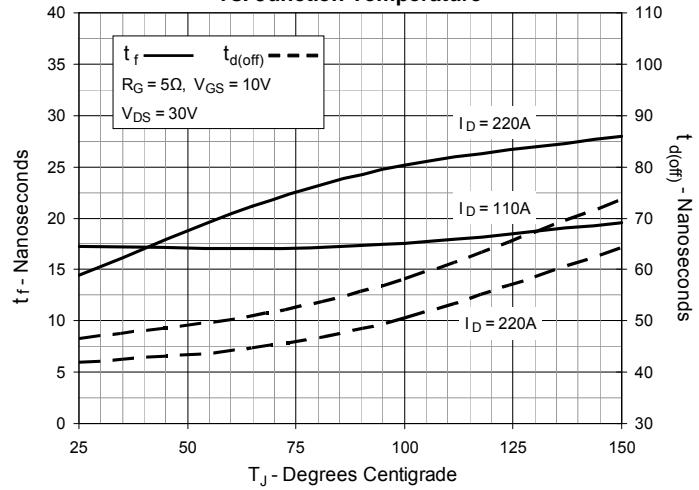
**Fig. 17. Resistive Turn-off Switching Times vs. Drain Current**



**Fig. 14. Resistive Turn-on Rise Time vs. Drain Current**



**Fig. 16. Resistive Turn-off Switching Times vs. Junction Temperature**



**Fig. 18. Resistive Turn-off Switching Times vs. Gate Resistance**

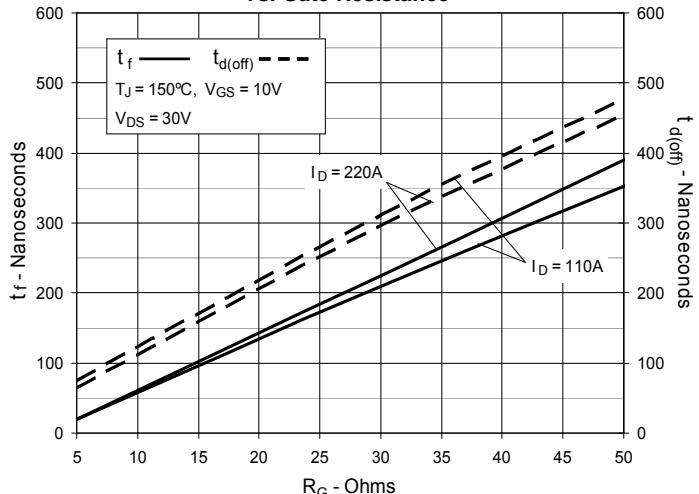
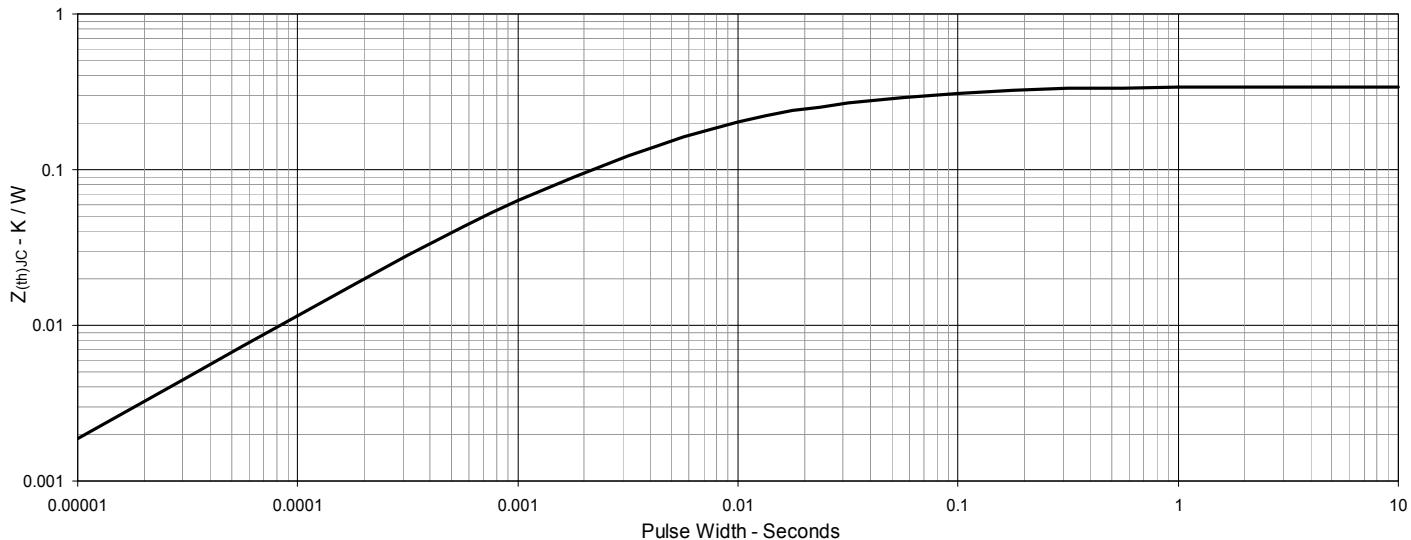
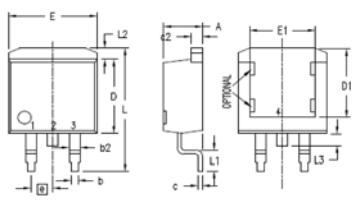
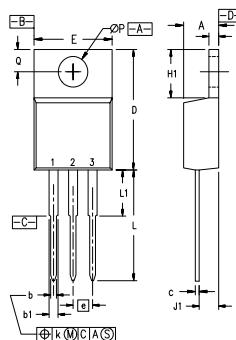


Fig. 19. Maximum Transient Thermal Impedance

**TO-263 Outline**

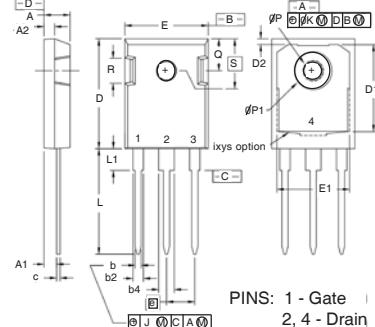
1 = Gate  
2 = Drain  
3 = Source  
4 = Drain

SYM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	.160	.190	4.06	4.83
A1	.080	.110	2.03	2.79
b	.020	.039	0.51	0.99
b2	.045	.055	1.14	1.40
c	.016	.029	0.40	0.74
c2	.045	.055	1.14	1.40
D	.340	.380	8.64	9.65
D1	.315	.350	8.00	8.89
E	.380	.410	9.65	10.41
E1	.245	.320	6.22	8.13
e	.100 BSC		2.54 BSC	
L	.575	.625	14.61	15.88
L1	.090	.110	2.29	2.79
L2	.040	.055	1.02	1.40
L3	.050	.070	1.27	1.78
L4	0	.005	0	0.13

**TO-220 Outline**

Pins: 1 - Gate      2 - Drain  
3 - Source

SYM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	.170	.190	4.32	4.83
b	.025	.040	0.64	1.02
b1	.045	.065	1.15	1.65
c	.014	.022	0.35	0.56
D	.580	.630	14.73	16.00
E	.390	.420	9.91	10.66
e	.100 BSC		2.54 BSC	
F	.045	.055	1.14	1.40
H1	.230	.270	5.85	6.85
J1	.090	.110	2.29	2.79
k	0	.015	0	0.38
L	.500	.550	12.70	13.97
L1	.110	.230	2.79	5.84
ØP	.139	.161	3.53	4.08
Q	.100	.125	2.54	3.18

**TO-247 Outline**

PINS: 1 - Gate  
2, 4 - Drain  
3 - Source

SYM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	.190	.205	4.83	5.21
A1	.090	.100	2.29	2.54
A2	.075	.085	1.91	2.16
b	.045	.055	1.14	1.40
b2	.075	.087	1.91	2.20
b4	.115	.126	2.92	3.20
C	.024	.031	0.61	0.80
D	.819	.840	20.80	21.34
D1	.650	.690	16.51	17.53
D2	.035	.050	0.89	1.27
E	.620	.635	15.75	16.13
E1	.545	.565	13.84	14.35
e	.215 BSC		5.45 BSC	
J	--	.010	--	0.25
K	--	.025	--	0.64
L	.780	.810	19.81	20.57
L1	.150	.170	3.81	4.32
ØP	.140	.144	3.55	3.65
ØP1	.275	.290	6.99	7.37
Q	.220	.244	5.59	6.20
R	.170	.190	4.32	4.83
S	.242 BSC		6.15 BSC	



---

Disclaimer Notice - Information furnished is believed to be accurate and reliable. However, users should independently evaluate the suitability of and test each product selected for their own applications. Littelfuse products are not designed for, and may not be used in, all applications. Read complete Disclaimer Notice at [www.littelfuse.com/disclaimer-electronics](http://www.littelfuse.com/disclaimer-electronics).

# X-ON Electronics

Largest Supplier of Electrical and Electronic Components

*Click to view similar products for [MOSFET](#) category:*

*Click to view products by [IXYS](#) manufacturer:*

Other Similar products are found below :

[614233C](#) [648584F](#) [IRFD120](#) [JANTX2N5237](#) [FCA20N60\\_F109](#) [FDZ595PZ](#) [2SK2545\(Q,T\)](#) [405094E](#) [423220D](#) [TPCC8103,L1Q\(CM](#)  
[MIC4420CM-TR](#) [VN1206L](#) [614234A](#) [715780A](#) [NTNS3166NZT5G](#) [SSM6J414TU,LF\(T](#) [751625C](#) [BUK954R8-60E](#) [NTE6400](#) [SQJ402EP-](#)  
[T1-GE3](#) [2SK2614\(TE16L1,Q\)](#) [2N7002KW-FAI](#) [DMN1017UCP3-7](#) [EFC2J004NUZTDG](#) [ECH8691-TL-W](#) [FCAB21350L1](#) [P85W28HP2F-](#)  
[7071](#) [DMN1053UCP4-7](#) [NTE221](#) [NTE222](#) [NTE2384](#) [NTE2903](#) [NTE2941](#) [NTE2945](#) [NTE2946](#) [NTE2960](#) [NTE2967](#) [NTE2969](#) [NTE2976](#)  
[NTE6400A](#) [NTE2910](#) [NTE2916](#) [NTE2956](#) [NTE2911](#) [DMN2080UCB4-7](#) [TK10A80W,S4X\(S](#) [SSM6P69NU,LF](#) [DMP22D4UFO-7B](#)  
[DMN1006UCA6-7](#) [DMN16M9UCA6-7](#)